# **UBEC / BBEC / ULEC -** 60+/40/20 GHz

Ultra Broadband Wire Bondable Embedded Silicon Capacitors



### **Key features**

- Ultra broadband performance up to 67 GHz
- Resonance free allowing ultra group delay variation
- Ultra low insertion loss thanks to an excellent impedance matching in transmission mode
- Low Esl and low ESR in bypass grounding mode
- High stability of capacitance value over temperature, voltage and aging
- High reliability
- Compatible with standard wire bonding assembly (ball and wedge) and embedding.

(please refer to our assembly application note for more details)

# **Key applications**

- Optoelectronics/high-speed data
- Trans-Impedance Amplifiers (TIA)
- Receive-and-Transmit Optical Sub-Assembly (ROSA/
- Synchronous Optical Networking (SONET)
- High speed digital logic
- Broadband test equipment
- Broadband microwave/millimeter wave
- Replacement of X7R and NPO capacitors
- Low profile applications (100 μm)

UBEC/BBEC/ULEC Capacitors target optical communication systems (ROSA/TOSA,SONET and all optoelectronics) as well as high speed data systems or products. The UBEC/BBEC/ULEC are designed for DC decoupling and bypass applications. The unique technology of integrated passive devices in silicon developed by Murata Integrated Passive Solutions, offers high rejection up to 67 GHz for the UBEC, up to 40 GHz for the BBEC and up to 20 GHz for the ULEC. These deep trench silicon capacitors have been developed with a semiconductor MOS process.

The UBEC/BBEC/ULEC capacitors provide very high reliability and capacitance stability over temperature (+60ppm/K) and voltage. They have and extended operating temperature range from -55 to 150°C. Reliable and repeatable performances are obtained thanks to a fully controlled production line with high temperature curing (above 900°C) generating a highly pure oxide. These capacitors are compatible with standard wire bonding assembly (ball and wedge). They are RoHS compliant and are available with thick Aluminum terminations for wire bonding and on request with thick copper terminations for embedding.



#### **UBEC 60 GHz electrical specifications**

Part number	Capacitance	BV	Case size	Thickness
935157725410-xxA	1 nF	30 V	0201M	100 µm
935157725456-xxA	5.6 nF	30 V	0201M	100 μm
935157425510-xxA	10 nF	11 V	0201M	100 μm
935157421610-xxA	100 nF	11 V	0404	100 μm

### BBEC 40 GHz electrical specifications

Part number	Capacitance	BV	Case size Thickness	
939132425510-xxA	10 nF	11 V	0201M	100 µm
939132421610-xxA	100 nF	11 V	0404	100 µm

# **ULEC 20 GHz electrical specifications**

Part number	Capacitance	BV	Case size Thicknes	
935158425510-xxA	10 nF	11 V	0201M	100 µm
935158421610-xxA	100 nF	11 V	0404	100 µm

Parameter	Value		
Capacitance range	1 nF to 100 nF(*)		
Capacitance tolerance	±15 %(*)		
Operating temperature range	-55 °C to 150 °C		
Storage temperature	-70 °C to 165 °C(**)		
Temperature coefficient	+60 pmm/K		
Breakdown voltage (BV)	11 VDC or 30 VDC		
Capacitance variation versus RVDC	0.1 % /V (from 0 V to RVDC)		
Insertion loss (IL) up to 60 GHz	<0.4 dB(***)		
Return Loss (RL) up to 60 GHz	>20 dB(***)		
Equivalent Series Inductance (ESL)	Typ. 100 pH(***) @ SRF		
Equivalent Series Resistance (ESR)	Typ. 30 mΩ (***)		
Insulation resistance	100 GΩ @ RVDC, @25°C, t>120s, for 100nF		
Ageing	Negligible, < 0.001% / 1000 h		
Reliability	FIT<0.017 parts / billion hours		
Capacitor height	Max 100 μm		
(*) Other values on request (**) w/o packing			

(\*\*\*) e.g. UBEC 10 nF/0201M/BV 11 V

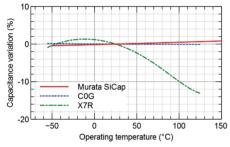


Fig. 1: Capacitance variation vs temperature (for UBEC/BBEC/ULEC and MLCC technologies)

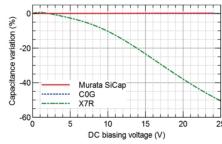


Fig.2: Capacitance variation vs DC biasing voltage @ BV 30 (for UBEC/BBEC/ULEC and MLCC technologies)

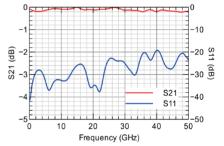


Fig.3: 5.6 nF/0201M UBEC BV30 measurement results (S-parameters in transmission mode with wire bonding de-embedded)

#Modelithics\* FREE S-Parameters-Based Linear Sim for ADS: http://www.modelithics.com

#### Capacitance range



Available parts. For other values, contact your Murata sales representative.

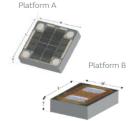
(1) 0201M-1nF and 5.6nF-BV30 available as UBEC only.

#### **Termination**

Can be directly mounted on the PCB using die bonding and wire bonding(s). Capacitors with top electrodes in 3 µm Aluminum (Al/Si/Cu). Other top finishings available on request (ex: Gold - TiWAu). Compatible with standard wire bonding assembly (ball and wedge) and embedding.

### **Package Outline**

	Case size (typ. +/-0.02mm)			
	L	W	T(****)	Platform
0201M	0.60	0.30	0.10	В
0404	1.06	1.06		А



### **Packaging**

Tape & reel (except for 0201M and 01005M), waffle pack, film frame carrier or raw wafer delivery.





#### Assembly by Wirebonding

The attachment techniques recommended by Murata for the UBEC/BBEC/ULEC capacitors on the customers substrates are fully detailed in specific documents available on our website. To assure the correct use and proper functioning of Murata Silicon capacitors please download the assembly instructions on www.murata.com and read them carefully.



For the assembly instructions, please go to :

www.murata.com/ and follow the sections : **⊃**Products

**⊃**Capacitor Silicon Capacitor **⊅UBEC/BBEC/ULEC** Series

Download the pdf file called: 'Assembly Note UBEC / BBEC / ULEC'

# Scan us, and visit our official Website to get more details:



https://www.murata.com/en-eu/products/capacitor/ siliconcapacitors/ubec\_bbec\_ulec

#### **Application Notes references**

For the application instructions, please refer to our documents:

- Storage and Shelf Life Conditions
- Recommendation to handle bare dies
- Nozzle recommendation

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